DATA SHEET

NPN SILICON GERMANIUM RF TRANSISTOR **NESG240034**

NPN SIGE RF TRANSISTOR FOR UHF-BAND, LOW NOISE, LOW DISTORTION AMPLIFICATION 3-PIN POWER MINIMOLD (34 PKG)

FEATURES

NEC

- The device is an ideal choice for low noise, low distortion amplification.
- NF = 0.7 dB TYP. @ VCE = 5 V, IC = 15 mA, f = 1 GHz
- Po (1 dB) = 24 dBm TYP. @ Vce = 5 V, Ic (set) = 40 mA, f = 1 GHz
- OIP₃ = 35.5 dBm TYP. @ Vce = 5 V, Ic (set) = 40 mA, f = 1 GHz
- Maximum stable power gain: MSG =11.5 dB TYP. @ VcE = 5 V, Ic = 40 mA, f = 1 GHz
- SiGe HBT technology (UHS2) : fr = 10.0 GHz
- This product is improvement of ESD of NESG2xxx series.
- 3-pin power minimold (34 PKG)

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG240034	NESG240034-A	3-pin power minimold (34 PKG) (Pb-Free)	25 pcs (Non reel)	Magazine case
NESG240034-T1	NESG240034-T1-A		1 kpcs/reel	12 mm wide embossed taping
				• Pin 2 (Collector) face the perforation side of the tape

Remark To order evaluation samples, please contact your nearby sales office. Unit sample quantity is 25 pcs.

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

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ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	5.5	V
Collector to Emitter Voltage	VCES	13	V
Collector to Emitter Voltage	VCEO	5.5	V
Base Current Note 1	Ів	36	mA
Collector Current	lc	400	mA
Total Power Dissipation	Ptot Note 2	886	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-65 to +150	°C

Notes 1. Depend on the ESD protect device.

2. Mounted on 3.8 cm \times 9.0 cm \times 0.8 mm (t) glass epoxy PWB

THERMAL RESISTANCE (TA = +25°C)

	Parameter	Symbol	Ratings	Unit
•	Termal Resistance from Junction to Ambient ^{™™}	Rth _{j-a}	141	°C/W

Note $\,$ Mounted on 3.8 cm \times 9.0 cm \times 0.8 mm (t) glass epoxy PWB $\,$

RECOMMENDED OPERATING RANGE (TA = +25°C)

	Parameter	Symbol	MIN.	TYP.	MAX.	Unit
<r></r>	Collector Current	lc	-	40	-	mA

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	$V_{CB} = 5 \text{ V}, \text{ I}_{E} = 0 \text{ mA}$	_	-	100	nA
Emitter Cut-off Current	Іево	$V_{\text{EB}}=0.4~\text{V},~\text{Ic}=0~\text{mA}$	_	-	100	nA
DC Current Gain		Vce = 5 V, Ic = 15 mA	140	180	260	-
RF Characteristics						
Gain Bandwidth Product	fт	Vce = 5 V, Ic = 40 mA, f = 1 GHz	_	10.0	-	GHz
Insertion Power Gain	S _{21e} ²	$V_{CE} = 5 \text{ V}, \text{ Ic} = 40 \text{ mA}, \text{ f} = 1 \text{ GHz}$	8.5	10.5	-	dB
Noise Figure (1)	NF1	$\label{eq:Vce} \begin{array}{l} V_{\text{CE}} = 5 \text{ V, Ic} = 15 \text{ mA, } f = 1 \text{ GHz}, \\ Z_{\text{S}} = Z_{\text{Sopt}}, \ Z_{\text{L}} = 50 \Omega \end{array}$	-	0.7	1.1	dB
Noise Figure (2)	NF2	$\label{eq:Vce} \begin{array}{l} V_{CE} = 5 \ V, \ I_C = 40 \ mA, \ f = 1 \ GHz, \\ Z_S = Z_{Sopt}, \ Z_L = Z_{Lopt} \end{array}$	-	0.9	-	dB
Associated Gain (1)	Gª1	$\label{eq:Vce} \begin{array}{l} V_{\text{CE}} = 5 \ V, \ I_{\text{C}} = 15 \ \text{mA}, \ f = 1 \ GHz, \\ Z_{\text{S}} = Z_{\text{Sopt}}, \ Z_{\text{L}} = 50 \Omega \end{array}$	8.0	10.0	_	dB
Associated Gain (2)	Gª2	$\label{eq:Vce} \begin{array}{l} V_{CE}=5~V,~I_{C}=40~mA,~f=1~GHz,\\ Z_{S}=Z_{Sopt},~Z_{L}=Z_{Lopt} \end{array}$	-	11.0	_	dB
Reverse Transfer Capacitance	Cre ^{Note 2}	$V_{CB} = 5 \text{ V}, \text{ I}_E = 0 \text{ mA}, \text{ f} = 1 \text{ MHz}$	_	1.1	1.3	pF
Maximum Stable Power Gain	MSG Note 3	Vce = 5 V, Ic = 40 mA, f = 1 GHz	9.5	11.5	-	dB
Gain 1 dB Compression Output Power	Po (1 dB)	$\label{eq:Vce} \begin{array}{l} V_{\text{CE}} = 5 \ V, \ I_{\text{C (set)}} = 40 \ \text{mA}, \ f = 1 \ \text{GHz}, \\ Z_{\text{S}} = Z_{\text{Sopt}}, \ Z_{\text{L}} = Z_{\text{Lopt}} \end{array}$	-	24	-	dBm
Output 3rd Order Intercept Point	OIP ₃	VcE = 5 V, Ic (set) = 40 mA, f = 1 GHz, ⊿f = 1 MHz, Zs = Zsopt, ZL = ZLopt	-	35.5	-	dBm

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

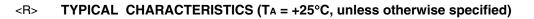
2. Collector to base capacitance when the emitter grounded.

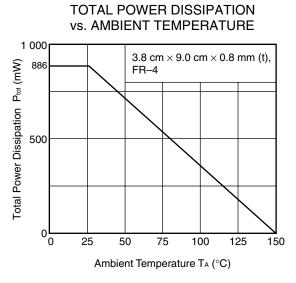
3. MSG =
$$\frac{S_{21}}{S_{12}}$$

hfe CLASSIFICATION

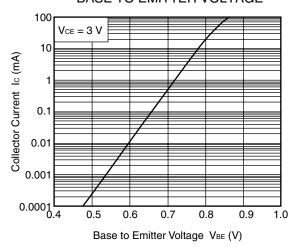
Rank	FB		
Marking	SR		
hfe Value	140 to 260		

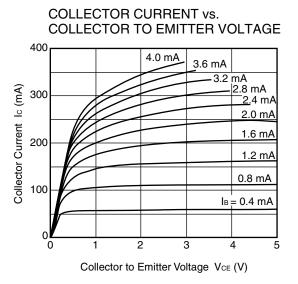




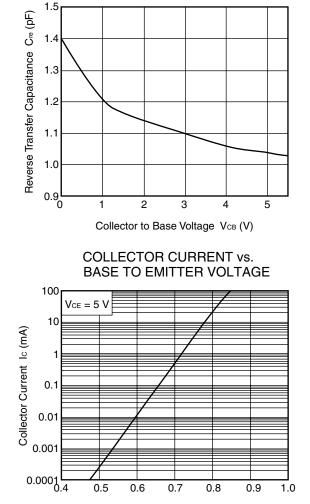


COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE





Remark The graphs indicate nominal characteristics.



REVERSE TRANSFER CAPACITANCE

vs. COLLECTOR TO BASE VOLTAGE

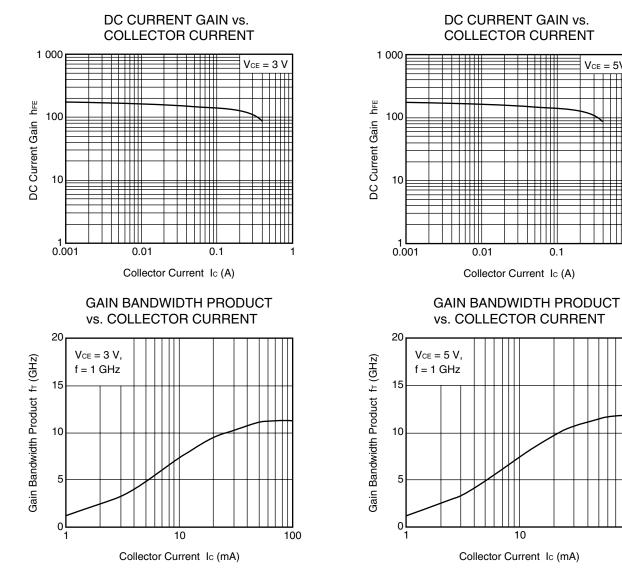
Base to Emitter Voltage VBE (V)

 $V_{CE} = 5V$ ŦĦ₩

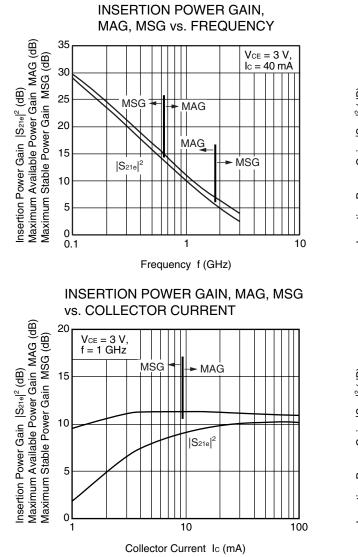
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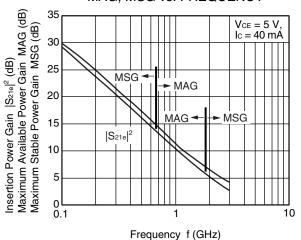


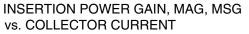
Remark The graphs indicate nominal characteristics.

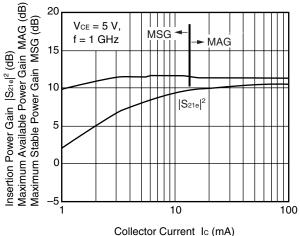


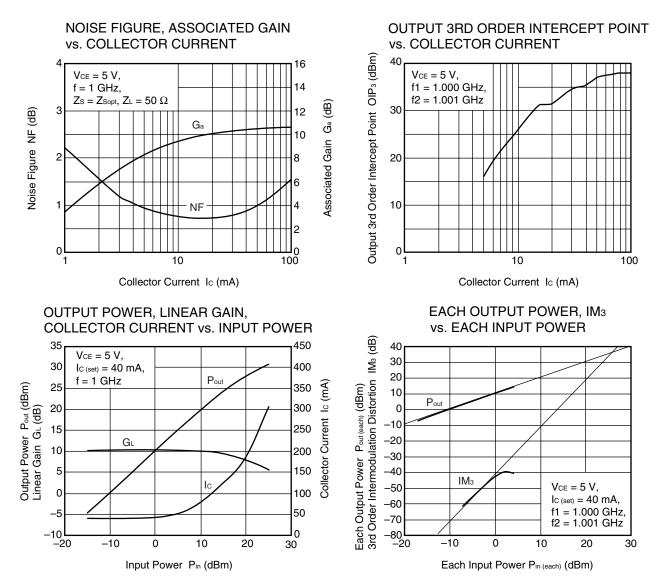
Remark The graphs indicate nominal characteristics.

INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY









Remark The graphs indicate nominal characteristics.

S-PARAMETERS

S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

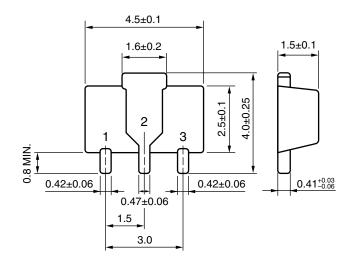
Click here to download S-parameters.

 $[\text{RF} \text{ and Microwave}] \rightarrow [\text{Device Parameters}]$

URL http://www.necel.com/microwave/en/

PACKAGE DIMENSIONS

3-PIN POWER MINIMOLD (34 PKG) (UNIT: mm)



PIN CONNECTIONS

- 1. Emitter
- 2. Collector
- 3. Base

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